Amendments to the Claims:

This listing of claims will replace all prior versions, and listings, of the claims in the application:

Listing of Claims:

1. (Currently Amended) A chemical vapor deposition system comprising: a eleaning first gas source eonfigured to generate a reactive cleaning gas; and fluidly coupled to a chemical vapor deposition chamber including a processing gas shower, a cleaning through a first gas distribution channel disposed within a lid of the chemical vapor deposition chamber, the lid further supporting a shower head disposed within the chemical vapor deposition chamber and separate from the processing gas shower first gas distribution channel, and said lid having an interior rim including a plurality of cleaning gas injection ports each of which is fluidly connected to the eleaning first gas distribution channel, and disposed and various ones of which are oriented at different angles with respect to introduce the cleaning gas into an interior of a wall of the chemical vapor deposition chamber, said wall being attached to said lid.

2 - 4. (Cancelled)

5. (Currently Amended) The chemical vapor deposition system of claim 1, wherein the plurality of cleaning gas injection ports include a first subset of the plurality of cleaning gas injection ports disposed at a first angle relative to side walls the interior of the wall of the chemical vapor deposition chamber, and a second subset of the plurality of cleaning gas injection ports disposed at a second angle relative to the side walls the interior of the wall.

6. (Cancelled)

- 7. (Currently Amended) The chemical vapor deposition system of claim 1, further including internal plumbing eonfigured to transport the reactive cleaning gas to coupling the eleaning first gas distribution channel to the first gas source, the internal plumbing being disposed within # the wall of the chemical vapor deposition chamber.
- 8. (Currently Amended) The chemical vapor deposition system of claim 1, further including a plurality of channel openings configured for reactive cleaning gas to enter coupling the internal plumbing to the cleaning gas distribution channel.

9. (Currently Amended) The chemical vapor deposition system of claim 1, further including a chamber collar configured to separate a separating the lid of the chemical vapor deposition chamber from walls of the chemical vapor deposition chamber, the chamber collar wall and including internal plumbing configured to supply reactive cleaning gas to coupling the cleaning gas distribution channel to the first gas source.

10 - 21. (Cancelled)